

# **RNB4580 Series**

# **Dual Low Noise Operational Amplifier**

REA03D0004-0100 Rev.1.00 Dec 25, 2006

#### **Description**

RNB4580 is dual bipolar low noise amplifiers designed for audio systems to improve tone control, audio pre-amplifier and industrial measurement tools. It also suitable for head phone amplifier at higher output current.

This product features internal frequency compensation, low noise, low distortion, high gain and high bandwidth. It also can operate under dual power supply voltage up to  $\pm 18$  V or single power supply up to 36 V.

The IC can be applied for the handy type set operational amplifier of general purpose in application of low voltage single supply type, which is properly biased of the input low voltage source.

#### **Features**

• Wide bandwidth: 15 MHz

• High speed: 7 V/μs

Low input noise voltage: 0.7 μVrms
 Large DC voltage gain: 110 dB
 Operating voltage: ±2 V to ±18 V

• Package outline available in Pb free lead frame:

DP-8 SOP-8 (JEITA) SOP-8 (JEDEC)

#### **Applications**

- Audio AC-3 decoder system
- · Audio amplifier
- Pre-amp
- Active filter

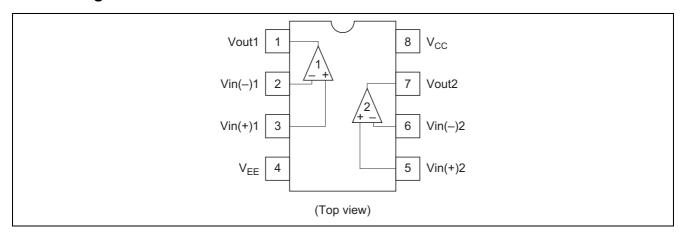
#### **Ordering Information**

| Type No.  | Application    | Package Code (Package Name) |
|-----------|----------------|-----------------------------|
| RNB4580   | Commercial use | PRDP0008AF-B (DP-8FV)       |
| RNB4580F  |                | PRSP0008DE-B (FP-8DGV)      |
| RNB4580RP |                | PRSP0008DD-C (FP-8DCV)      |

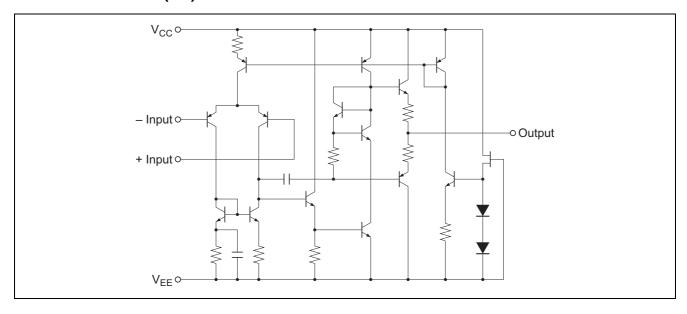
Note: This product is designed for consumer use and not for automotive.



## **Pin Arrangement**



## Circuit Schematic (1/2)



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

|                            |                                | Ratings            |                    |                    |      |
|----------------------------|--------------------------------|--------------------|--------------------|--------------------|------|
| Item                       | Symbol                         | RNB4580            | RNB4580F           | RNB4580RP          | Unit |
| Supply Voltage             | Vcc                            | 18                 | 18                 | 18                 | V    |
|                            | V <sub>EE</sub>                | -18                | -18                | -18                | V    |
| Differential input voltage | V <sub>IN</sub> (diff)         | ±30                | ±30                | ±30                | V    |
| Common mode input voltage  | V <sub>CM</sub> * <sup>3</sup> | ±15                | ±15                | ±15                | V    |
| Power dissipation          | P <sub>T</sub>                 | 670 * <sup>1</sup> | 385 * <sup>2</sup> | 385 * <sup>2</sup> | mW   |
| Operating temperature      | Topr                           | -40 to +85         | -40 to +85         | -40 to +85         | °C   |
| Storage temperature        | Tstg                           | -55 to +125        | -55 to +125        | -55 to +125        | °C   |

Notes: 1. This is the allowable value up to  $Ta = 45^{\circ}C$ . Derate by 8.3 mW/°C above that temperature.

- 2. These are the allowable values up to Ta =  $60^{\circ}$ C mounting on  $40\text{mm} \times 40\text{mm} \times 1.6\text{mm}$  (t) 10% wiring density glass epoxy board. Derate by 5.9 mW/°C above that temperature.
- 3. If the supply voltage is less than  $\pm 15$  V, input voltage should be less than supply voltage.

#### **Electrical Characteristics**

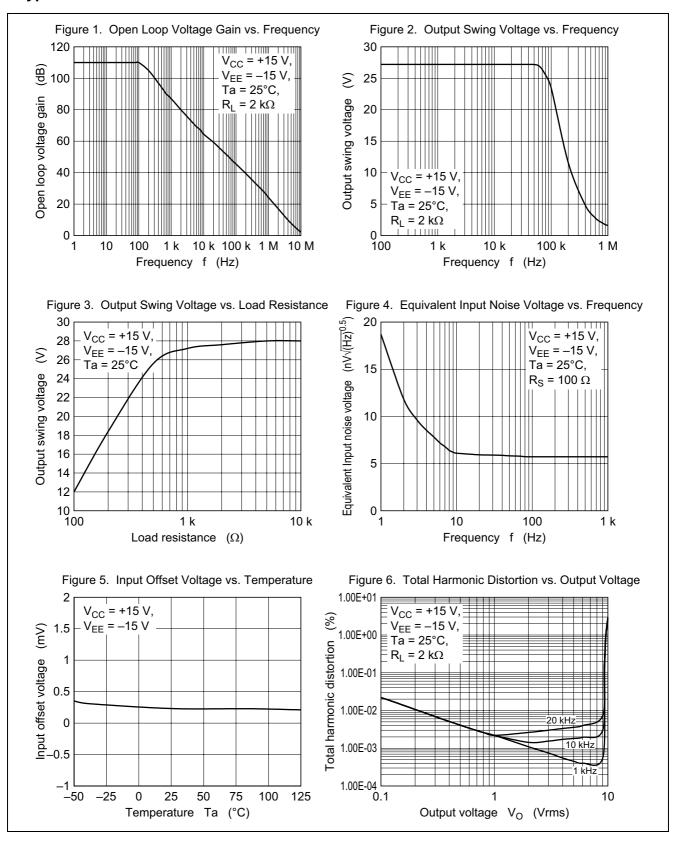
 $(Ta = 25^{\circ}C, V_{CC} = +15 \text{ V}, V_{EE} = -15 \text{ V}, \text{ unless otherwise specified})$ 

| Item                            | Symbol             | Min | Тур    | Max | Unit  | Test Conditions   |
|---------------------------------|--------------------|-----|--------|-----|-------|---|
| Input offset voltage            | V <sub>IO</sub>    | _   | 0.5    | 3   | mV    | $R_S \le 10 \text{ k}\Omega$  |
| Input offset current            | I <sub>IO</sub>    | _   | 5      | 100 | nA    |   |
| Input bias current              | I <sub>IB</sub>    |     | 150    | 500 | nA    |   |
| Supply current                  | Icc                | _   | 4      | 7   | mA    |   |
| Power supply rejection ratio    | PSRR               | 80  | 110    | _   | dB    | $R_S \le 10 \text{ k}\Omega$  |
| Voltage gain                    | A <sub>V</sub>     | 90  | 110    | _   | dB    | $R_L \ge 2 \text{ k}\Omega, V_O = \pm 10 \text{ V}$   |
| Common mode rejection ratio     | CMR                | 80  | 110    | _   | dB    | $R_S \le 10 \text{ k}\Omega$ , $V_{CM} = 0 \text{ V to}$  |
| Output sink current             | I <sub>OSINK</sub> | _   | 80     | _   | mA    | $V_{CC} = -1.5 \text{ V}$ $V_{IN(-)} = 1 \text{ V}, V_{IN(+)} = 0 \text{ V},$ $V_{O} = 2 \text{ V}$ |
| Output source current           | Iosource           | _   | 45     | _   | mA    | $V_{IN(-)} = 0 \text{ V}, V_{IN(+)} = 1 \text{ V},$<br>$V_{O} = 2 \text{ V}$                        |
| Input common mode voltage range | V <sub>ICM</sub>   | ±12 | ±13.5  | _   | V     |   |
| Slew rate                       | SR                 | _   | 7      | _   | V/μs  |   |
| Equivalent input noise voltage  | V <sub>NI</sub>    | _   | 0.7    | _   | μVrms | RIAA, $R_S = 2.2 \text{ k}\Omega$ , 30 kHz LPF  |
| Gain bandwidth product          | GBP                | _   | 15     | _   | MHz   | $f = 10 \text{ kHz}, R_L = 2 \text{ k}\Omega$   |
| Total harmonic distortion       | THD                | _   | 0.0005 | _   | %     | $A_V = 20 \text{ dB}, V_O = 5 \text{ V},$ $R_L = 2 \text{ k}\Omega, f = 1 \text{ kHz}$              |

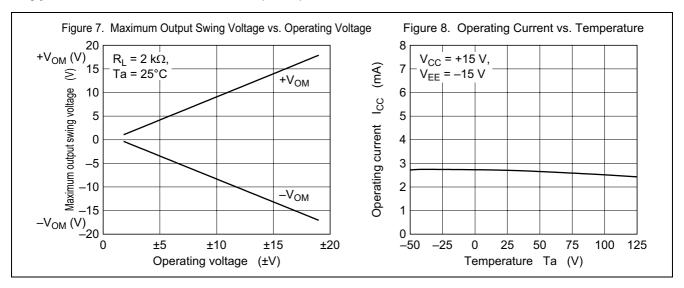
# **Table of Graphs**

| Elec                           | Figure                             |   |
|--------------------------------|------------------------------------|---|
| Open loop voltage gain         | vs. Frequency f                    | 1 |
| Output swing voltage           | vs. Frequency f                    | 2 |
| Output swing voltage           | vs. Load resistance R <sub>L</sub> | 3 |
| Equivalent input noise voltage | vs. Frequency f                    | 4 |
| Input offset voltage           | vs. Temperature Ta                 | 5 |
| Total harmonic distortion      | vs. Output Voltage Vo              | 6 |
| Maximum output voltage swing   | vs. Operating voltage V            | 7 |
| Operating current              | vs. Temperature Ta                 | 8 |

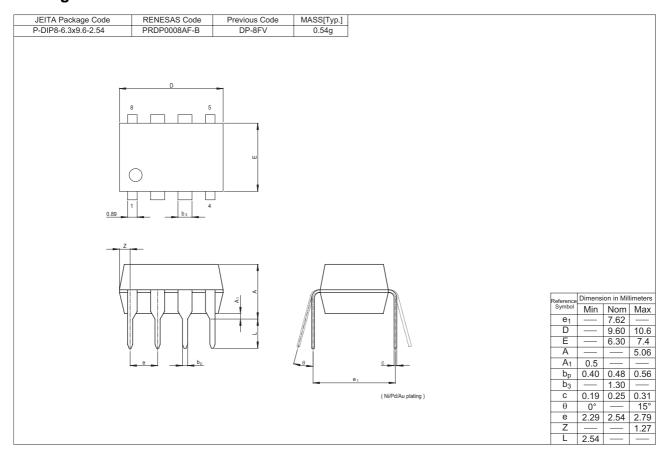
### **Typical Characteristics Curves**

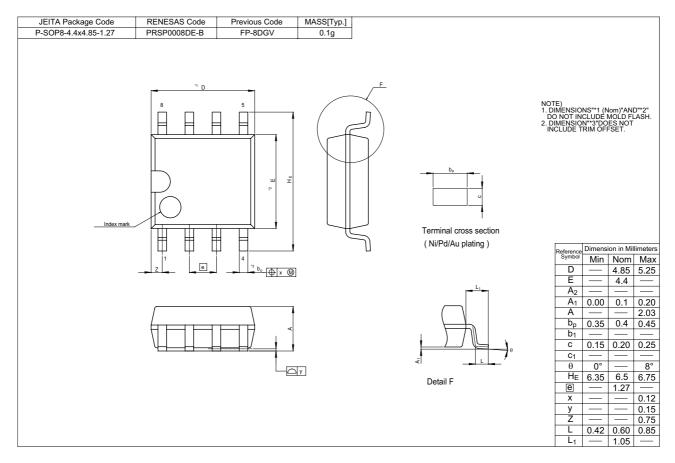


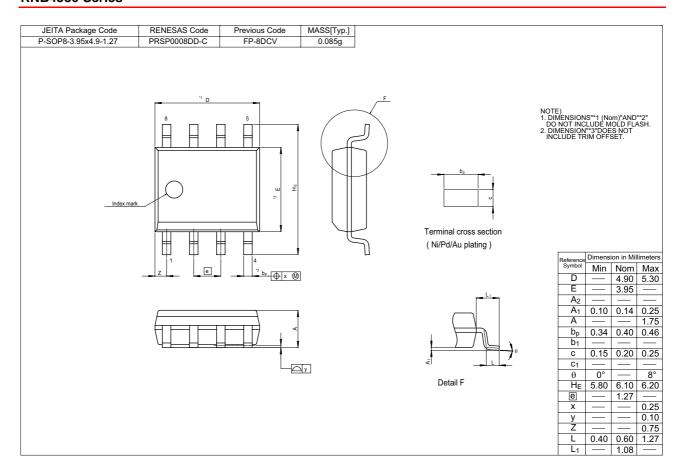
### **Typical Characteristics Curves (cont.)**



### **Package Dimensions**







#### Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

- Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

  Notes:

  1. This document is provided for reference purposes only so that Renesas customers may select the appropriate Renesas products for their use. Renesas neither makes warranties or representations with respect to the accuracy or completeness of the information in this document nor grants any license to any intellectual property rights or any other rights of Renesas or shy third party with respect to the information in this document.

  2. Renesas shall have no liability for damages or infringement of any intellectual property or other rights arising out of the use of any information in this document, but not limited to, product data, diagrams, algorithms, and application circuit examples.

  3. You should not use the products or the technology described in this document for the purpose of military applications such as the development of weapons of mass and regulations, and procedures required by such laws and regulations and procedures required by such laws and regulations, and procedures required by such laws and regulations. All procedures required by such laws and regulations and procedures required by such laws and regulations and procedures required by such laws and regulations. All procedures required by such laws and regulations and procedures required by such laws and regulations, and procedures required by such laws and regulations, and procedures are such as a result of errors or omissions in the information with a Renesas sales office of the date of



**RENESAS SALES OFFICES** 

http://www.renesas.com

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

**Renesas Technology America, Inc.** 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd. Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology Singapore Pte. Ltd. 1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510